

# 1.5A Ultra-small Load Switch with Slew Rate Control

# **FEATURES**

Integrated P-channel MOSFET load switch

Input voltage: 1.2V to 5.5V

1.5A maximum continuous switch current

Switch on-resistance(typ.):

Rdson= $50m\Omega$  at  $V_{IN}=5.5V$ 

Rdson= $56m\Omega$  at  $V_{IN}=4.2V$ 

Rdson= $64m\Omega$  at  $V_{IN}=3.3V$ 

Rdson= $78m\Omega$  at  $V_{IN}=2.5V$ 

Rdson= $109m\Omega$  at  $V_{IN}=1.8V$ 

Rdson= $225m\Omega$  at  $V_{IN}=1.2V$ 

Controlled slew rate to limit inrush current

Internal EN Pull-Down Resistor

Quick output discharge

FOCSP 0.76mm×0.76mm×0.50mm-4B package

#### **APPLICATIONS**

- Smartphones and Tablets
- Portable Devices
- Wearables

# **GENERAL DESCRIPTION**

The AW35121 is a load switch with output slew rate control. The device integrates a  $64m\Omega$  (typ.) P-channel MOSFET, which can operate over a wide input range of 1.2V to 5.5V.

The AW35121 features output slew rate control, limiting inrush current during turn-on to protect downstream devices.

# TYPICAL APPLICATION CIRCUITS

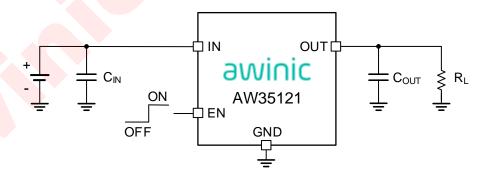


Figure 1 Typical Application circuit of AW35121

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# PIN CONFIGURATION AND TOP MARK

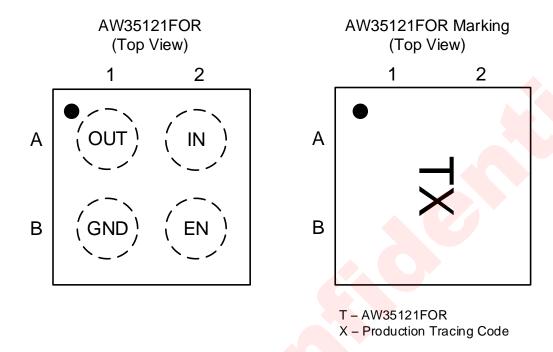


Figure 2 Pin Configuration and Top Mark

# **PIN DEFINITION**

Pin	Name	Description
A1	OUT	Switch output
A2	IN	Switch input and power supply
B1	GND	Device ground
B2	EN	Switch control input, active high, internal 7.1MΩ pull down resistor.

# **FUNCTIONAL BLOCK DIAGRAM**

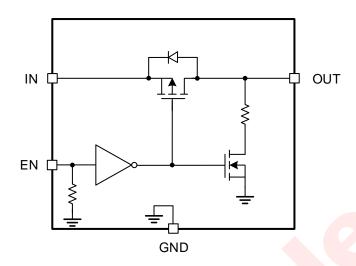


Figure 3 Functional Block Diagram

# **TYPICAL APPLICATION CIRCUITS**

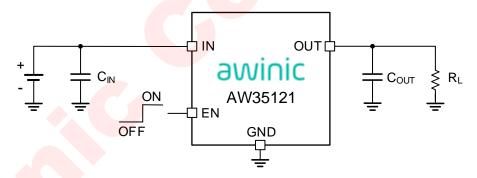


Figure 4 Typical Application circuit of AW35121

# **ORDERING INFORMATION**

Part Number	Temperature	Package	Marking	Moisture Sensitivity Level	Environmental Information	Delivery Form
AW35121FOR	-40°C∼85°C	FOCSP 0.76mm×0.76 mm-4B	Т	MSL1	ROHS+HF	3000 units/ Tape and Reel



# **ABSOLUTE MAXIMUM RATINGS**(NOTE1)

PARAMETER	RANGE					
Supply Voltage Rai	-0.3V to 6V					
Input Voltage Range	Input Voltage Range EN					
Output Voltage Range	OUT	-0.3V to 6V				
Maximum Continuous Switch Curre	ent for VIN ≥ 2V <sup>(NOTE 2)</sup>	1.5A				
Maximum Peak Switch Current for	or VIN ≥ 2.5V <sup>(NOTE 3)</sup>	2A				
Junction-to-ambient Thermal R	esistance θ <sub>JA</sub> (NOTE 4)	184°C/W				
Operating Free-air Tempe	rature Range	-40°C to 85°C				
Maximum Junction Temp	150°C					
Storage Temperatu	-65°C to 150°C					
Lead Temperature (Solderin	260°C					
ESD						
HBM (Human Body Mo	odel) (NOTE 5)	±2kV				
CDM(Charged Device N	±1.5kV					
MM(Machine Model	±200V					
Latch-Up (NOTE	+IT : 200mA					
Lateri-op		-IT:-200mA				

NOTE1: Conditions out of those ranges <u>listed in "absolute maximum ratings"</u> may cause permanent damages to the device. In spite of the limits above, functional operation conditions of the device should within the ranges listed in "recommended operating conditions". Exposure to absolute-maximum-rated conditions for prolonged periods may affect device reliability.

NOTE2: Limited by thermal design.

NOTE3: Limited by thermal design, and tested in 10ms width pulse current.

NOTE4: Thermal resistance from junction to ambient is highly dependent on PCB layout.

NOTE5: The human body model is a 100pF capacitor discharged through a 1.5k $\Omega$  resistor into each pin. Test method: ESDA/JEDEC JS-001-2017.

NOTE6: All pins. Test Condition: ESDA/JEDEC JS-002-2014.

NOTE7: All pins. Test Condition: JESD22-A115C.

NOTE8: Test Condition: JESD78E.

# RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min.	Тур.	Max.	Unit
VIN	Input Voltage			5.5	V
V <sub>EN</sub>	EN Voltage			5.5	V
Vout	Output Voltage			Vin	V
Cin	Input capacitance		1		μF
Соит	Output load capacitance	0.1	1		μF



# **ELECTRICAL CHARACTERISTICS**

 $T_A = -40$ °C to 85°C unless otherwise noted. Typical values are guaranteed for  $V_{IN} = 5V$ ,  $C_{IN} = 1\mu F$ ,  $I_{IN} \le 1.5A$  and  $T_A = 25$ °C.

PARAMETER		TEST CONDITION	MIN	TYP	MAX	UNIT
INPUT	CURRENTS					
		V <sub>IN</sub> =3.3V, V <sub>EN</sub> =3.3V, I <sub>OUT</sub> =0A, T <sub>A</sub> =25°C		2	12	nA
	Input quiescent	V <sub>IN</sub> =3.3V, V <sub>EN</sub> =3.3V, I <sub>OUT</sub> =0A, T <sub>A</sub> =85°C		9		nA
lα	current	V <sub>IN</sub> =5.5V, V <sub>EN</sub> =5.5V, I <sub>OUT</sub> =0A, T <sub>A</sub> =25°C		5	25	nA
		V <sub>IN</sub> =5.5V, V <sub>EN</sub> =5.5V, I <sub>OUT</sub> =0A, T <sub>A</sub> =85°C		10		nA
		V <sub>IN</sub> =1.2V, V <sub>EN</sub> =0V, T <sub>A</sub> =25°C		2		nA
		V <sub>IN</sub> =1.8V, V <sub>EN</sub> =0V, T <sub>A</sub> =25°C		2		nA
		V <sub>IN</sub> =3.3V, V <sub>EN</sub> =0V, T <sub>A</sub> =25°C		4	44	nA
	Shutdown	V <sub>IN</sub> =4.0V, V <sub>EN</sub> =0V, T <sub>A</sub> =25°C		7		nA
I <sub>SD</sub>	current from IN	V <sub>IN</sub> =4.5V, V <sub>EN</sub> =0V, T <sub>A</sub> =25°C		22		nA
	to GND	V <sub>IN</sub> =5.0V, V <sub>EN</sub> =0V, T <sub>A</sub> =25°C		62	970	nA
		V <sub>IN</sub> =5.0V, V <sub>EN</sub> =0V, T <sub>A</sub> =55°C		90		nA
		V <sub>IN</sub> =5.0V, V <sub>EN</sub> =0V, T <sub>A</sub> =85°C		350		nA
		V <sub>IN</sub> =5.5V, V <sub>EN</sub> =0V, T <sub>A</sub> =25°C		171		nA
ILEAKEN	EN pin leakage current	V <sub>IN</sub> =0V, V <sub>EN</sub> =5.0V			1.5	μΑ
$R_{EN}$	EN pin pull down resistor	V <sub>EN</sub> =5.0V		6.85		ΜΩ
POWER	SWITCH					
		VIN=5.5V, VEN=high, IOUT=200mA, TA=25°C		50		
		V <sub>IN</sub> =4.2V, V <sub>EN</sub> =high, I <sub>OUT</sub> =200mA, T <sub>A</sub> =25°C		56		
R <sub>dson</sub>	Internal switch MOSFET on-	V <sub>IN</sub> =3.3V, V <sub>EN</sub> =high, I <sub>OUT</sub> =200mA, T <sub>A</sub> =25°C		64		mΩ
Rason	state resistance	$V_{IN}$ =3.0V, $V_{EN}$ =high, $I_{OUT}$ =200mA, $T_{A}$ =25°C		68	120	11152
		V <sub>IN</sub> =1.8V, V <sub>EN</sub> =high, I <sub>OUT</sub> =200mA, T <sub>A</sub> =25°C		109		
		V <sub>IN</sub> =1.2V, V <sub>EN</sub> =high, I <sub>OUT</sub> =200mA, T <sub>A</sub> =25°C		225		
R <sub>DIS</sub>	Output discharge resistance	ischarge VIN=3.3 V, VEN=IOW, TA=23 C,		75	100	Ω
<b>t</b> <sub>R</sub>	Output rise time	V <sub>IN</sub> =3.6V, C <sub>OUT</sub> =1μF, R <sub>OUT</sub> =30Ω		165		μs
t <sub>F</sub>	Output fall time	V <sub>IN</sub> =3.6V, C <sub>OUT</sub> =1μF, R <sub>OUT</sub> =30Ω		42		μs
t <sub>ON</sub> Switch turn on time		$V_{IN}$ =3.6 $V$ , $C_{OUT}$ =1 $\mu$ F, $R_{OUT}$ =30 $\Omega$		238		μs



PA	RAMETER	TEST CONDITION	MIN	TYP	MAX	UNIT
toff	Switch turn off time	V <sub>IN</sub> =3.6V, C <sub>OUT</sub> =1 $\mu$ F, R <sub>OUT</sub> =30 $\Omega$		12		μs
ten	Enable time	V <sub>IN</sub> =3.6V, C <sub>OUT</sub> =1μF, R <sub>OUT</sub> =30Ω		130		μs
VIH	EN input high threshold level		1.2			٧
VIL	EN input low threshold level				0.5	V

# **TIMING DIAGRAM**

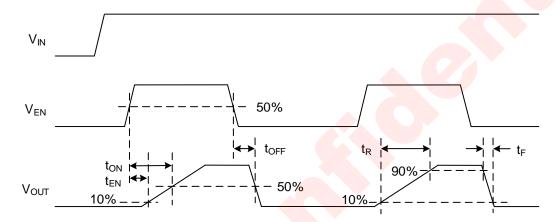
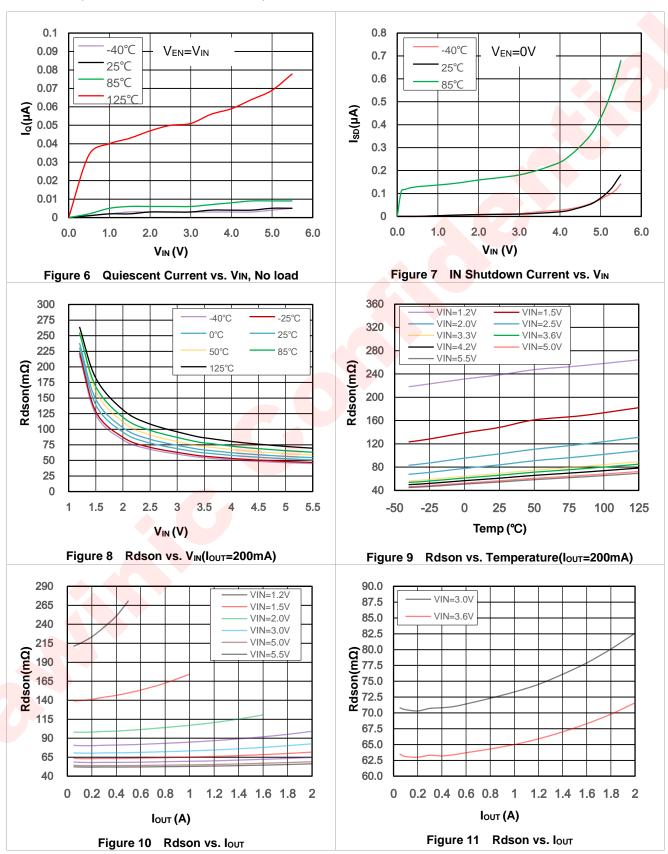


Figure 5 AW35121 Timing Diagram

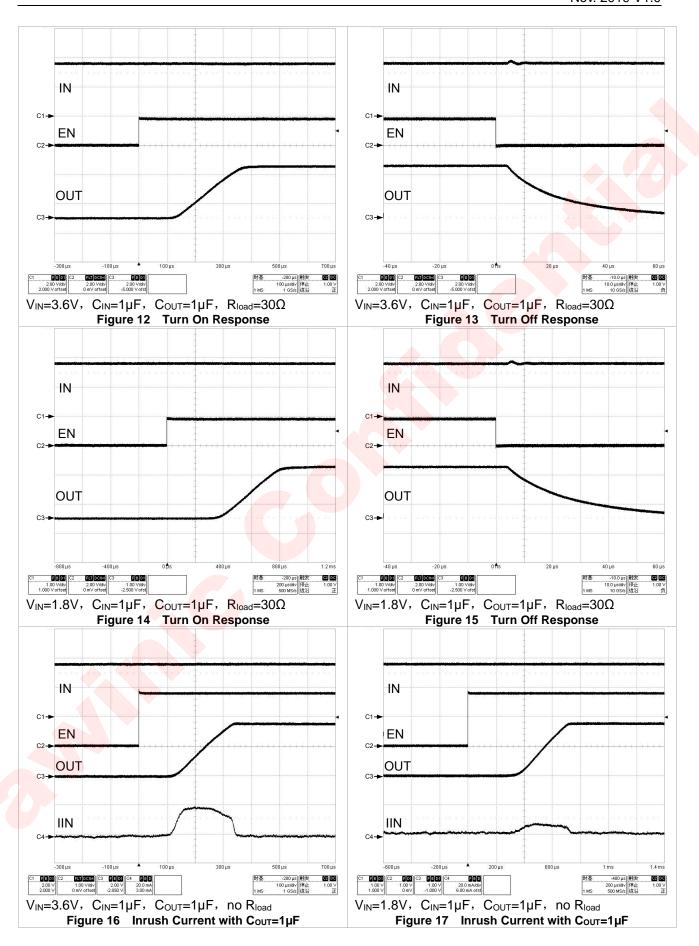


# TYPICAL CHARACTERISTICS

Ambient temperature is 25°C,  $C_{IN} = C_{OUT} = 1 \mu F$ , unless otherwise noted.









# **DETAILED FUNCTIONAL DESCRIPTION**

The AW35121 integrates a high side P channel MOSFET load switch, and provides a low on-resistance for a low voltage drop across the device. A controlled slew rate is used in applications to limit the inrush current. The part can be turned on, with a supply voltage from 1.2V to 5.5V.

#### **TURN ON/OFF CONTROL**

Enable pin is active high. The device is opened when EN pin is tied low (disable) or pulled down by internal  $7.1M\Omega$  resistor, forcing PMOS switch off. The IN/OUT path is activated with a minimum Vin of 1.2V and EN forced to high level.

**Table 1. Functional Table** 

EN	IN to OUT	OUT to GND	
Low	OFF	ON	
High	ON	OFF	

#### **SLEW RATE CONTROL**

When the switch is enabled, the device regulates the gate voltage of MOSFET, and controls the  $V_{OUT}$  slew rate during  $t_R$  to avoid a large input inrush current. The feature reduces the interference to the power supply.

#### QUICK OUTPUT DISCHARGE

The AW35121 includes the Quick Output Discharge (QOD) feature, in order to discharge the application capacitor connected on OUT pin. When EN pin is set to low level (disable state), a discharge resistance with a typical value of  $75\Omega$  connected between the output and ground, pulls down the output and prevents it from floating.

Nov. 2019 V1.0

# **APPLICATION INFORMATION**

#### POWER SUPPLY RECOMMENDATIONS

The device is designed to operate with a  $V_{IN}$  range of 1.2V to 5.5V. This supply must be well regulated and placed as close to the device terminals as possible. It must also be able to withstand all transient and load currents, using a recommended input capacitance of  $1\mu F$  if necessary. If the supply is located more than a few inches from the device terminals, additional bulk capacitance may be required in addition to the ceramic bypass capacitors. If additional bulk capacitance is required, an electrolytic, tantalum, or ceramic capacitor of  $10\mu F$  may be sufficient.

#### MANAGING INRUSH CURRENT

When the switch is enabled, the output capacitors must be charged up from 0V to V<sub>IN</sub>. A input inrush current will appear. The Inrush current can be calculated using Equation 1:

$$Iinrush = Cout \frac{dVout}{dt}$$
 (1)

where:

- Cout = Output capacitance
- dVout = Output voltage, equals to Vin
- $dt = Rise time t_R$ .

The AW35121 offers a controlled slew rate for minimizing inrush current.

#### **POWER DISSIPATION**

The power dissipation produced by the power MOSFET Rdson in ON-state can be calculated with the following equation:

$$PD = Rdson \times (IOUT)^{2}$$
 (2)

Where:

- P<sub>D</sub> = Power dissipation (W)
- Rdson = Power MOSFET on resistance ( $\Omega$ )
- I<sub>OUT</sub> = Output current (A)

#### THERMAL CONSIDERATIONS

Main contributor in term of junction temperature T<sub>J</sub>(max) is the power dissipation, and T<sub>J</sub>(max) should be restricted to 125°C under ON-state. Junction temperature is directly proportional to power dissipation in the device, it can be calculated by the following equation:

$$T_{J} = T_{A} + R_{\theta JA} \times P_{D} \tag{3}$$

Where:

- T<sub>J</sub> = Junction temperature of the device
- T<sub>A</sub> = Ambient temperature
- P<sub>D</sub> = Power dissipation of the device
- Reja = Junction to ambient thermal resistance. This parameter is highly dependent on board layout.



# **PCB LAYOUT CONSIDERATION**

AW35121 is a low ON-Resistance load switch. In order to obtain the optimal performance, PCB layout should be considered carefully. Here are some guidelines:

- 1. All the peripherals should be placed as close to the device as possible. Place the input capacitor C<sub>IN</sub> on the top layer (same layer as the AW35121) and close to IN pin, and place the output capacitor C<sub>OUT</sub> on the top layer (same layer as the AW35121) and close to OUT pin.
- 2. The AW35121 integrate an up to 1.5A rated PMOS FET, and the PCB design rules must be respected to properly evacuate the heat out of the silicon. By increasing PCB area, especially around IN and OUT pins, the  $R\theta_{JA}$  of the package can be decreased, allowing higher power dissipation. Red bold paths on Figure 18 are power lines that will flow large current, please route them on PCB as straight, wide and short as possible.
- 3. Use rounded corners on the power trace from the power supply connector to AW35121 to decrease EMI coupling.

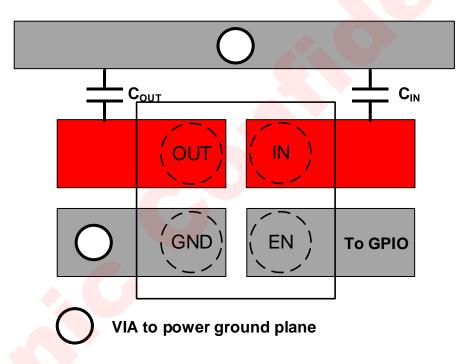
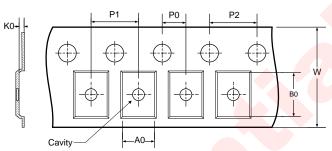


Figure 18 PCB layout example

# TAPE AND REEL INFORMATION

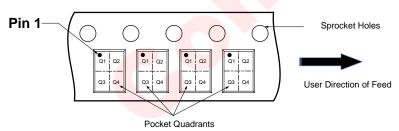
# **REEL DIMENSIONS** 0 D1

# TAPE DIMENSIONS



- A0: Dimension designed to accommodate the component width
- B0: Dimension designed to accommodate the component length
- K0: Dimension designed to accommodate the component thickness
- W: Overall width of the carrier tape
- P0: Pitch between successive cavity centers and sprocket hole
- P1: Pitch between successive cavity centers
- P2: Pitch between sprocket hole
- D1: Reel Diameter
- D0: Reel Width

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

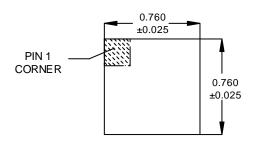


# **DIMENSIONS AND PIN1 ORIENTATION**

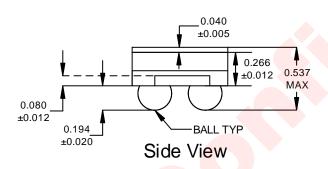
Ī	D1	D0	A0	B0	K0	P0	P1	P2	W	Pin1 Quadrant
	(mm)	Pin i Quadrant								
	179	9.20	0.85	0.85	0.59	2.00	4.00	4.00	8.00	Q1

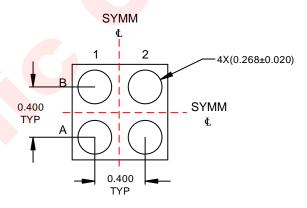
All dimensions are nominal

# **PACKAGE DESCRIPTION**



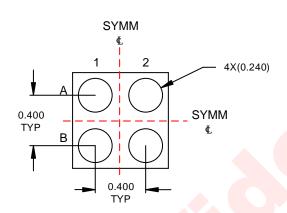
Top View

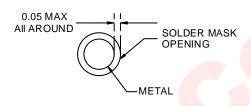


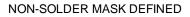


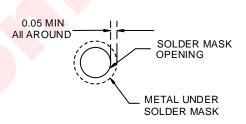
**Bottom View** 

# **LAND PATTERN DATA**









SOLDER MASK DEFINED

Unit: mm



# **REVISION HISTORY**

Version	Date	Change Record
V1.0	Nov 2019	Datasheet V1.0 Released



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